

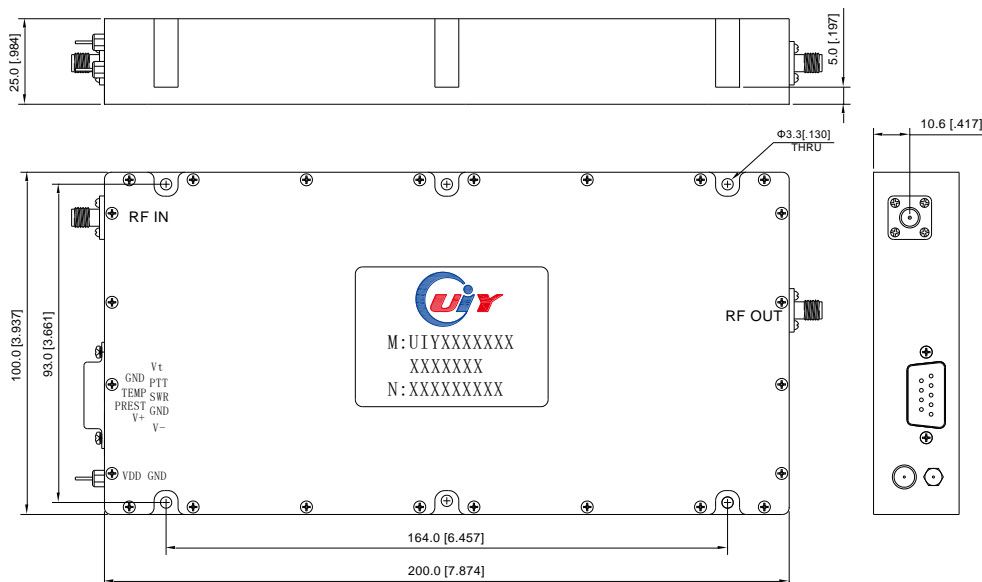
20 to 512MHz 120W – Power Amplifier

UIYPA200100B20T512SF

RF Characteristics @T=25°C, VDD=+28VDC; 50Ω System					
Parameter	Symbol	Min	Type	Max	Unit
Operating Frequency	BW	20		512	MHz
Power Output CW	Po	100	120		W
Saturation Output Power		120			
Power Gain @CW	G	50	53		dB
Input Power	Pin		-3	0	dBm
Gain Flatness	ΔG		±1.5	±2.0	dB
Input VSWR	S11		1.5:1		
Odd Harmonics @CW	H	-12	-15		dBc
Even Harmonics @CW	H	-15	-20		dBc
Noise Figure	NF		6	8	dB
Spurious Signals	Spur		-60		dBc
Operating Voltage	VDC		28	30	Volt
Current Consumption @Po=100W	ID		9	12	A
Operating Temperature	Tc	-40		+60	°C
Storage Temperature	Tstg	-55		+70	°C
Connector Type	Input SMA Female, Output SMA Female				
<ul style="list-style-type: none"> ◇ Listed are specific frequency ranges and other ranges are available. ◇ Please provide the below information when inquiring and mark * is required. <ul style="list-style-type: none"> * 1. The specific pass band frequency range * 2. The specific Gain and Power * 3. Other special requests. 					

Mechanical Drawing

Note: External heatsink is needed in this module



GND: Grounding
 PTT: High level work, low level or hanging on shutdown.
 Temp: Over temperature protection, output high level at +70°C, PA shutdown.
 SWR: VSWR output protection, output VSWR>3 or open circuit, output high level, PA shutdown.
 Vt: PA Temperature, Vt=0.5V+TC×10mV/°C.
 V+: Forward RF power Indicator.
 V-: Reversed RF power Indicator.
 Prest: Reset function, when it occurs protection, send a pulse signal, it can reset.
 VDD: Working Voltage: +28V.

Unit: mm/ inch, General part tolerance is ±2% unless otherwise stated.

Ver. 5.1